NSN 5961-01-275-4631

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The state of the s
Inclosure Material:
Metal
Overall Length:
1.573 inches
Overall Height:
0.360 inches
Overall Width:
1.050 inches
End Application:
Lgm 30
Mounting Facility Quantity:
2
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-204ae
Electrode Internally-electrically Connected To Case:
Drain
Mounting Method:
Unthreaded hole
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 drain to gate voltage and 200.0 drain to source voltage and 20.0 gate to source voltage
Power Rating Per Characteristic:
150.0 watts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Special Features:
Nuclear hardness critical item
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
0bdc6-13-1330005 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 pin and 1 case
Specification Data:
81349-mil-prf-19500/543 government specification
Shelf Life:

N/a

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Init	<i>(</i>)+	Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.